Docket No.: 3905
USSN: 09/519,408
Title: Semiconductor Light-Emitting Device, Method of Manufacturing Transparent Conductor Film and Method of Manufacturing Compound Semiconducotr Light-Emitting Device

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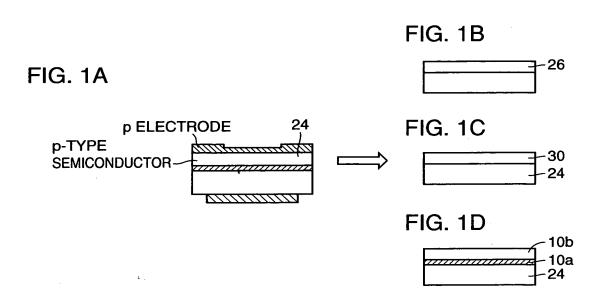
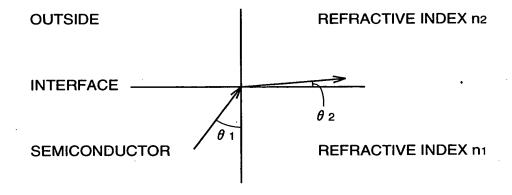


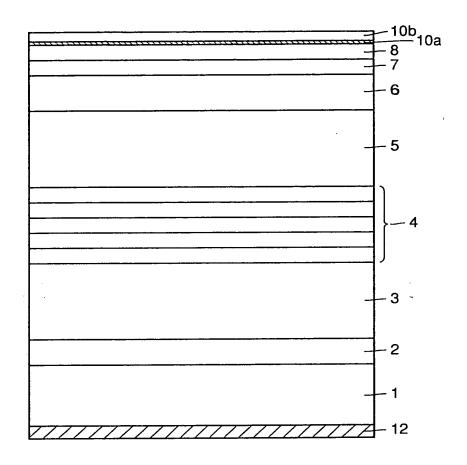
FIG. 3





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FIG. 2





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FIG. 4

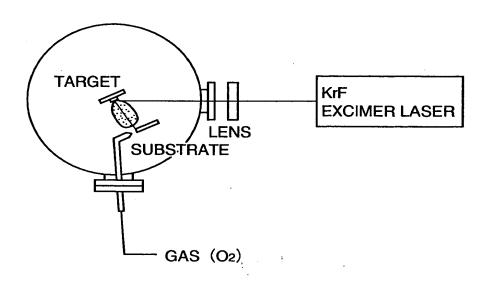
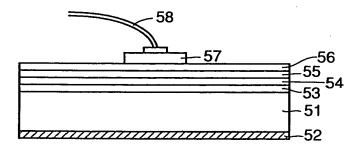
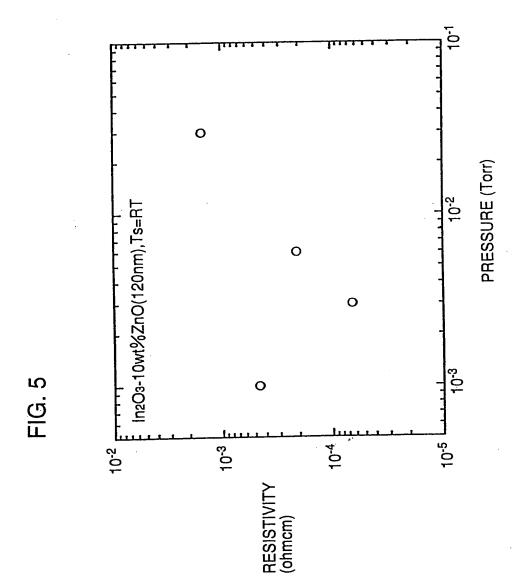


FIG. 8



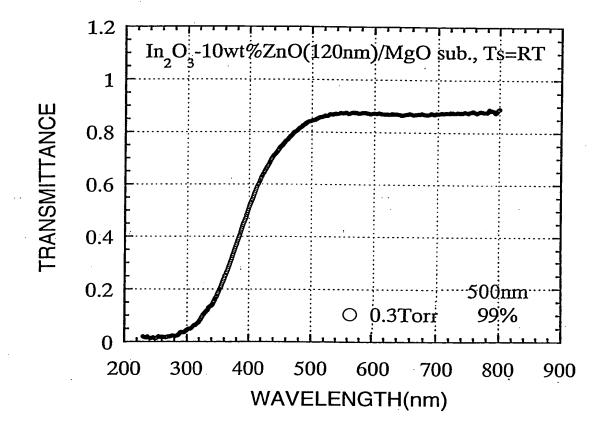






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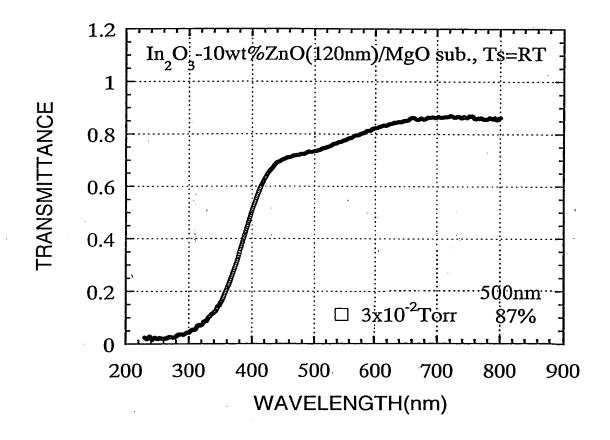
FIG. 6A





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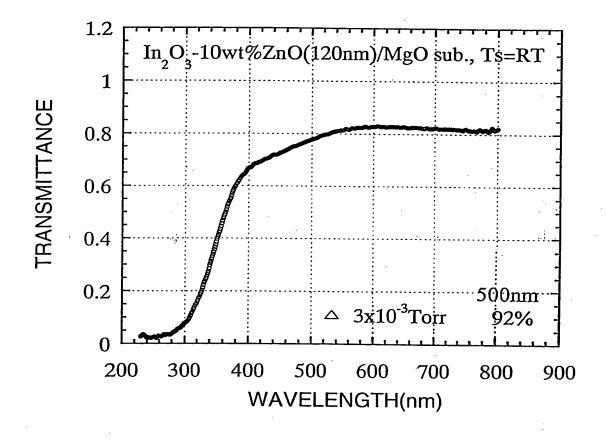
FIG. 6B





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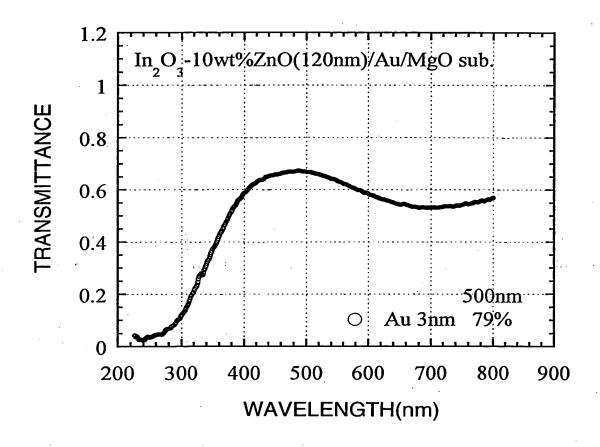
FIG. 6C





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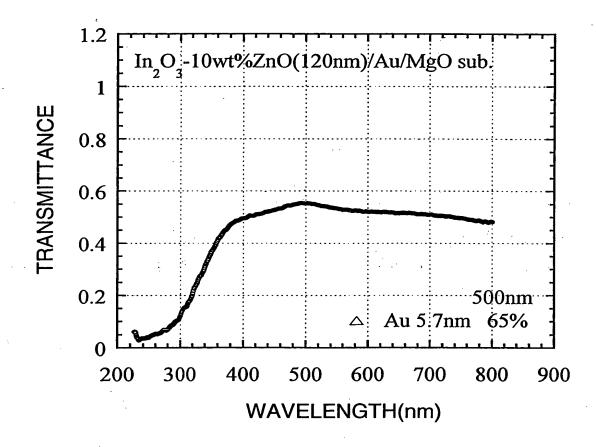
FIG. 7A





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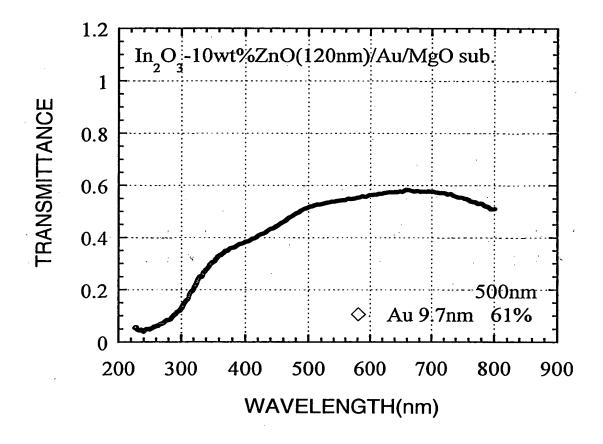
FIG. 7B





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FIG. 7C





LUMINESCENT CENTER Eg o o o o o o o o o VALENCE BAND CONDUCTION BAND INJECTION OF HOLES - p REGION p-n JUNCTION PRIOR ART INJECTION OF ELECTRONS FIG. 9B 0 n REGION -EMITTING REGION PRIOR ART FIG. 9A p LAYER n ELECTRODE p ELECTRODE



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FIG. 10 PRIOR ART

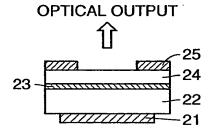


FIG. 11 PRIOR ART

